
APPLICATION DATA SHEET UNDER 37 C.F.R. §1.76

Inventor Information

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Application Information

Title: METHOD OF EPITAXY ON A SILICON SUBSTRATE
COMPRISING AREAS HEAVILY DOPED WITH ARSENIC

Total Drawing Sheets: 4

Formal Drawings? Yes

Application Type: Non-Provisional Utility

Art Unit: Unknown

Docket Number: S1022/8562

Representative Information

Representative Customer Number:: 23628

Continuity Information

This application is a: Non-provisional

Claiming priority to: Non-Provisional application docket nos. S1022/8562 and S1022/8072

Serial Number: Not yet assigned

Filing Date: July 10, 2001

Status: Pending

Prior Foreign Applications

Foreign Application Number: 97/10032

Filing Date: July 31, 1997

Country: France

Priority Claimed: Yes

Assignee Information (when available)

Name of Assignee: STMicroelectronics S.A.

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